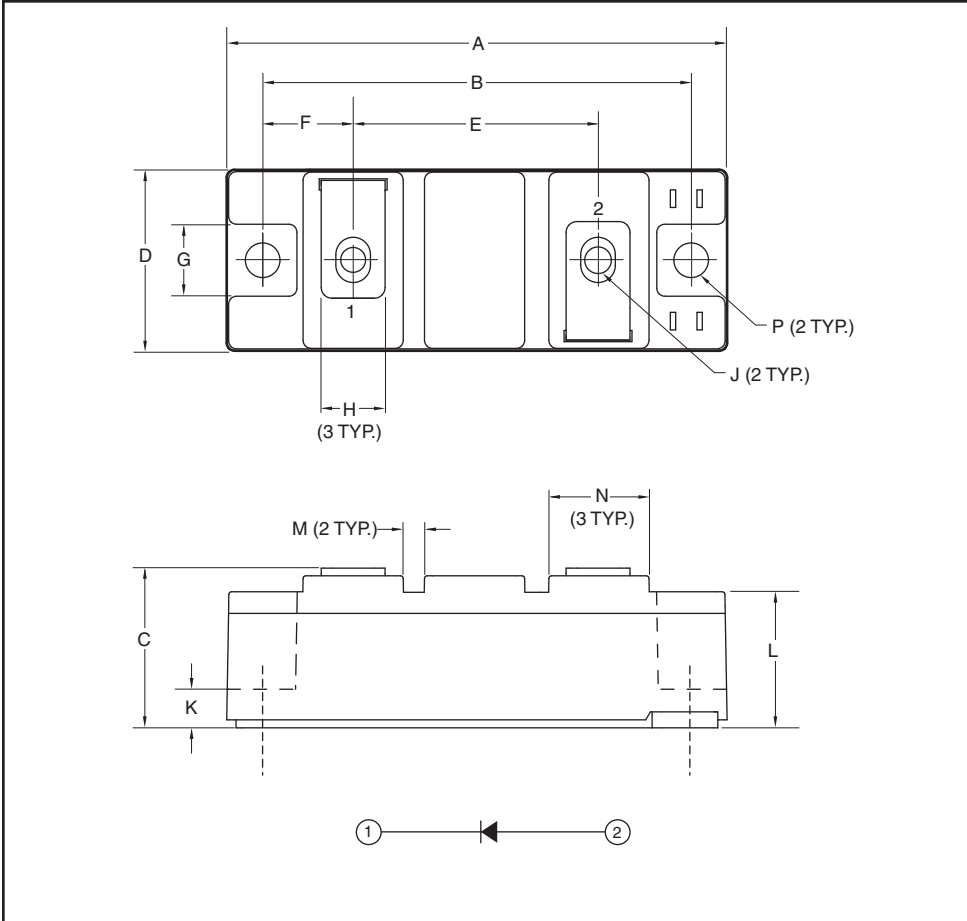


### Super Fast Recovery Diode Modules 280 Amperes/1200 Volts



Outline Drawing and Circuit Diagram

Dimensions	Millimeters
A	94
B	80
C	30
D	34
E	46
F	17
G	13

Dimensions	Millimeters
H	12
J	M6
K	7.5
L	25.4
M	4
N	19
P	6.5 Dia.



**Description:**

Powerex Super Fast Recovery Single Diode Modules are designed for use in applications requiring fast switching. The modules are isolated for easy mounting with other components on common heatsinks.

**Features:**

- Super Fast Recovery Time
- RoHS Compliant
- Isolated Mounting
- Metal Baseplate
- Low Thermal Impedance
- 2500V Isolating Voltage

**Applications:**

- Free Wheeling
- Welding and Plasma Cutting Machine

**QRS1240R30**

**Super Fast Recovery Single Diode Modules**

280 Amperes/1200 Volts

**Absolute Maximum Ratings,  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Ratings	Symbol	QRS1240R30	Units
Repetitive Peak Reverse Blocking Voltage	$V_{RRM}$	1200	Volts
Non-Repetitive Peak Reverse Blocking Voltage	$V_{RSM}$	$V_{RRM} + 100$	Volts
DC Current, $T_C = 80\text{ }^\circ\text{C}$ (Resistive Load)	$I_{F(DC)}$	280	Amperes
Peak Half Cycle Non-repetitive Surge Current ( $t = 8.3\text{mS}$ , 100% $V_{RRM}$ Reapplied)	$I_{FSM}$	TBD	Amperes
$I^2t$ for Fusing for One Cycle ( $t = 8.3\text{mS}$ , 100% $V_{RRM}$ Reapplied)	$I^2t$	TBD	$\text{A}^2\text{sec}$
Operating Junction Temperature	$T_j$	-40 to 150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-40 to 150	$^\circ\text{C}$
Maximum Mounting Torque, M6 Mounting Screw	—	26	in-lb
Maximum Mounting Torque, M6 Terminal Screw	—	26	in-lb
Module Weight (Typical)	—	180	Grams
V Isolation (60 Hz, Circuit to Base, All Terminals Shorted, $t = 60\text{ sec}$ )	$V_{RMS}$	2500	Volts

**Electrical Characteristics,  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Reverse Leakage Current	$I_{RRM}$	Rated $V_{RRM}$	—	—	1.0	mA
On-State Voltage	$V_{FM}$	$I_F = 200\text{A}$	—	2.4	3.2	Volts
		$I_F = 280\text{A}$	—	2.7	3.5	Volts
Reverse Recovery Time	$t_{rr}$	$I_f = 200\text{A}$ , $di/dt = \text{TBD}$	—	—	150	ns
Reverse Recovery Charge	$Q_{rr}$	$I_f = 200\text{A}$ , $di/dt = \text{TBD}$	—	19.2	—	$\mu\text{C}$

**Thermal and Mechanical Characteristics,  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction to Case*	$R_{th(j-c)}$ Q	Per Diode	—	—	0.075	$^\circ\text{C}/\text{W}$
Contact Thermal Resistance, Case to Sink (Lubricated)*	$R_{th(c-s)}$	Per Module	—	—	0.05	$^\circ\text{C}/\text{W}$

\* $T_C$ ,  $T_f$  measured point is just under the chip.

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